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► **To cite this version:**

Jacob Szeftel, Nicolas Sandeau, Michel Abou Ghantous. Study of the Superconducting to Normal Transition. *Journal of Superconductivity and Novel Magnetism*, 2020, 33 (5), pp.1307-1316. 10.1007/s10948-019-05393-1 . hal-02568151

HAL Id: hal-02568151

<https://hal.science/hal-02568151v1>

Submitted on 8 May 2020

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Study of the superconducting to normal transition

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(Dated: December 23, 2019)

A model, based on classical mechanics and thermodynamics and valid for *all* superconductors, is devised to investigate the properties of the *current-driven*, superconducting to normal transition. This process is shown to be reversible. An original derivation of the BCS variational procedure is given. Two different critical temperatures are introduced. The temperature dependence of the critical current is worked out and found to agree with observation. The peculiar transport properties of high- T_c compounds in the normal state and old magnetoelastic data are also interpreted within this framework. A novel experiment is proposed to check the relevance of this analysis to high- T_c superconductivity.

PACS numbers: 74.25.Bt, 74.25.Fy, 74.25.Ha

I. INTRODUCTION

Shortly after the discovery of superconductivity, it was realized that applying a growing magnetic field¹⁻⁴ H turns superconducting electrons into normal ones at a critical value $H = H_c$. Besides, this process has been characterized as a reversible first order transition, i.e. decreasing H from H_c down to 0 brings normal electrons back to the superconducting state. However, this experimental procedure suffers from several drawbacks, when scrutinized from a thermodynamical standpoint :

- because all experiments have been made so far¹⁻¹⁰ at fixed temperature T , the heat exchanged during the transition remains unknown. Likewise, since nobody bothered to measure the work performed by H , the binding energy of the superconducting phase with respect to the normal one E_b could not be assessed with help of the first law of thermodynamics. Meanwhile the formula $E_b = \mu_0 H_c^2 / 2$ was assumed¹¹, with μ_0 being the magnetic permeability of vacuum, and became eventually ubiquitous in textbooks¹⁻⁴. Unfortunately, a numerical application in case of Al turns out to underestimate¹² by ten orders of magnitude the E_b value, deduced from the BCS theory¹³;
- due to the Meissner effect¹² and the finite ac conductivity³ in the superconducting state, the current density is spatially inhomogeneous^{12,14,15} and there is no one-to-one correspondence between the external magnetic field and the current distribution inside the sample, so that *qualitative* information only can be achieved from H mediated experiments¹⁻¹⁰. At last, letting high T_c compounds go normal requires a huge, often impractical magnetic field⁵⁻¹⁰.

Consequently, despite countless published H_c data^{1-10,17,18}, there is still no theory of the super-

conducting to normal transition, apart from the phenomenological¹⁻⁴ approach, based on the grossly wrong assumption $E_b = \mu_0 H_c^2 / 2$. Thus the purpose of the present article is to design one, valid for *both* high and low T_c superconductors, as well. Accordingly, since it has been argued recently¹⁶ that feeding a growing current into a superconductor drives *continuously* the superconducting phase to the normal one, this article will focus on a theoretical account of the *current-driven*, superconducting to normal transition. Such an experimental procedure enables one to dodge all of the shortcomings mentioned above, in particular because reliable data for the critical current are available in all superconductors, including those for which H_c is so large that it cannot be reached experimentally. Furthermore it allows for a *quantitative* treatment, unlike the H mediated procedure. At last, since the current, carried by the superconducting electrons, plays a paramount role hereafter, it is worth mentioning an original view¹⁹, which establishes the common significance of the persistent currents²⁰ and Josephson effect²¹.

The purpose of this work is then twofold :

- this transition will be studied with help of Newton's law and thermodynamics;
- the resulting findings will be taken advantage of to shed light into the transport properties of high T_c compounds in the controversial^{17,18,22,23} $T > T_c$ range and the magneto-elastic behaviour, observed in elementary superconductors^{24,25} for $T \leq T_c$.

The outline is as follows : the electro-dynamical and thermodynamical properties of the superconducting to normal transition are worked out in sections 2, 3, respectively; a new derivation of the BCS calculation is given in section 4, which enables us to define two critical temperatures and to reckon the T dependent critical current; this analysis is further applied to investigate the transport properties of high- T_c compounds for $T > T_c$, in

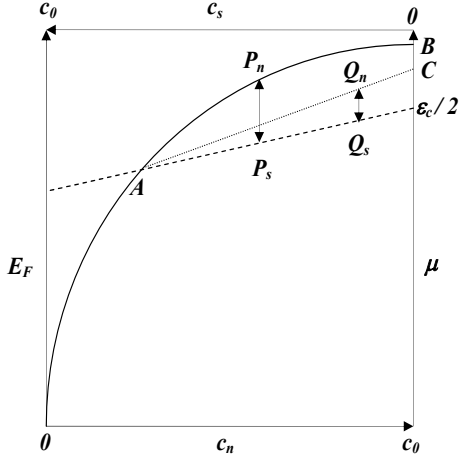


FIG. 1. schematic plots of $E_F(T < T_c, c_n)$ and $\mu(c_s)$ as solid and dashed lines, respectively; the origin $E_F = \mu = 0$ is set at the bottom of the conduction band; the tiny difference $E_F(T, c_n) - \mu(c_0 - c_n)$ has been hugely magnified for the reader's convenience; the crossing point A between the solid and dashed lines represents the electron system in thermal equilibrium at T, T_* , according to Eq.(1); the isothermal process, addressed in sections 2, 3 is pictured by the P_n, P_s pair, whereas the dotted line and the Q_n, Q_s pair illustrate the adiabatic process, discussed in section 5

section 5; magneto-elastic data^{24,25} are discussed in section 6; the results of this work are summarized in the conclusion.

II. ELECTRODYNAMICAL DISCUSSION

As done previously^{12,14-16}, our analysis will proceed within the two-fluid model. Accordingly, the conduction electrons make up a homogeneous mixture of normal and superconducting electrons, in concentration c_n, c_s , respectively. The normal electrons behave like a Fermi gas²⁶, characterised by T and the Fermi energy E_F . The Helmholtz free energy of independent electrons per unit volume F_n and E_F are related^{26,27} by $E_F = \frac{\partial F_n}{\partial c_n}$. By contrast, the superconducting electrons are organised as a many bound electron state¹⁶ of eigenenergy per unit volume $\mathcal{E}_s(c_s)$, such that its chemical potential reads $\mu = \frac{\partial \mathcal{E}_s}{\partial c_s}$. Gibbs and Duhem's law²⁷ entails that the thermal equilibrium is characterised by

$$E_F(T, c_n(T)) = \mu(c_s(T)) \quad , \quad (1)$$

with $c_0 = c_n(T) + c_s(T)$ and c_0 being the concentration of conduction electrons.

Consider then a superconducting material of cylindrical shape, characterized by its symmetry axis z and radius r_0 in a cylindrical frame with coordinates (r, θ, z) and flown through, along the z direction, by a time dependent current $I(t) = \pi r_0^2 j(t)$, with $j(t)$ being a uniform current density. The analysis of an isothermal, current-driven, superconducting to normal transition, outlined

elsewhere¹⁶, will be developed below with $j(t) = \gamma t, \gamma > 0$. Accordingly, the initial state of the whole electron system is defined as $j(0) = 0, c_n = c_n(T), c_s = c_s(T)$ (see A in Fig.1). As $j(t)$ increases at constant T , the electron system shifts away from the equilibrium position in A : the Fermi gas, represented by P_n in Fig.1, moves, along the solid line, towards B , corresponding to the normal state $c_n = c_0$, while the superconducting electrons, represented by P_s , go, along the dashed line, towards the point characterized¹⁶ by $\mu(c_s = 0) = \frac{\epsilon_c}{2}$ (ϵ_c refers to the Cooper pair energy²⁸). As this process will be shown to be reversible, the pair P_n, P_s , will shift back along the solid and dashed lines and will eventually merge into A , if j is brought back down to 0. The rest of section 1 below deals with a detailed, quantitative account of the isothermal process, outlined above and illustrated in Fig.1.

Due to $\gamma = \frac{dj}{dt} \neq 0$, Newton's law reads^{12,14-16} for the normal and superconducting current densities $j_n(t), j_s(t)$ ($\Rightarrow j = j_n + j_s$; note that j_s is also referred¹⁹ to as a *collective mode current*)

$$\tau_n \frac{dj_n}{dt} = \sigma_n E - j_n \quad , \quad \tau_s \frac{dj_s}{dt} = \sigma_s (E - E_{s \rightarrow n}) - j_s. \quad (2)$$

E and τ_n, τ_s are, respectively, the applied electric field and the decay times of j_n, j_s , due to friction with the lattice, responsible for Ohm's law, whereas $\sigma_n = \frac{c_n e^2 \tau_n}{m}, \sigma_s = \frac{c_s e^2 \tau_s}{m}$ stand for the normal and superconducting conductivities^{14,15} ($\tau_n \ll \tau_s \Rightarrow \sigma_n \ll \sigma_s$) and m, e refer to the effective²⁶ mass and charge of an electron. Moreover τ_s being finite has been demonstrated elsewhere¹⁵ and shown¹⁶ furthermore to be consistent with observation of persistent currents at $E = 0$. The effective field $E_{s \rightarrow n}$ is defined with respect to $f_{s \rightarrow n} = c_s e E_{s \rightarrow n}$, the interelectron force, which turns superconducting electrons into normal ones. The resulting $f_{s \rightarrow n}$ is mediated by the interelectron coupling, also responsible for the binding energy of the superconducting electrons, i.e. $E_b > 0$. Actually $E_{s \rightarrow n}$ was neglected in previous^{12,14-16} works ($\Rightarrow j_s \approx \sigma_s E$). But, as it will appear below that $|\frac{E_{s \rightarrow n}}{E}| \ll 1$, such an approximation was fully vindicated.

During the elementary time-duration δt , superconducting electrons in concentration δc_s , moving at the mass center velocity^{12,14-16} v_s ($\Rightarrow v_s = \frac{j_s}{c_s e}$), are driven normal at vanishing velocity by $f_{s \rightarrow n}$, which corresponds to a momentum variation per unit volume of $\delta p = -m \delta c_s v_s$. Thence $f_{s \rightarrow n}$ is inferred from Newton's law to read

$$f_{s \rightarrow n} = \frac{\delta p}{\delta t} = -\frac{m \dot{c}_s}{c_s e} j_s \Rightarrow E_{s \rightarrow n} = -\frac{m \dot{c}_s}{(c_s e)^2} j_s \quad , \quad (3)$$

with $\dot{c}_s = \frac{dc_s}{dt}$. Then combining Eqs.(2,3), while recalling that the inertial force $\propto \frac{dj_s}{dt}$ is negligible^{12,14}, yields

$$E = \frac{j_n}{\sigma_n} = \frac{j_s}{\sigma_s} + E_{s \rightarrow n} \Rightarrow \frac{j_n}{\sigma_n} = \frac{j_s}{\sigma_s^*} = \frac{j}{\sigma_n + \sigma_s^*} \quad . \quad (4)$$

$$\sigma_s^* = \frac{\sigma_s}{1 - \tau_s \frac{\dot{c}_s}{c_s}}$$

Eq.(4) conveys the same meaning as Ohm's law, written for j_n, j_s flowing parallel to each other, except for the effective conductivity σ_s^* showing up instead of σ_s .

The elementary work δW , needed for one superconducting electron, moving with velocity v_s , to go normal with vanishing velocity, is reckoned to be equal to $\delta W = \frac{mv_s^2}{2} = \frac{m}{2} \left(\frac{j_s}{c_s e} \right)^2$, thanks to the kinetic energy theorem. On the other hand, for an isothermal process, δW is also equal to the difference of free energy²⁷ between the superconducting and normal states, which leads thence to the identity²⁷ $\delta W = \frac{\partial E_n}{\partial c_n} - \frac{\partial \mathcal{E}_s}{\partial c_s} = E_F(T, c_n) - \mu(c_s)$. Consequently, j_s reads finally

$$j_s(c_s) = c_s e \sqrt{\frac{2}{m} (E_F(T, c_0 - c_s) - \mu(c_s))} \quad . \quad (5)$$

Note that, unlike the normal current $j_n = \sigma_n E$, j_s is *independent* from the external field E and depends only on the *concentration* of bound electrons c_s .

Eq.(4) can now be recast as an ordinary differential equation of first order for the unknown $c_s(j)$

$$\gamma \frac{d \log c_s}{dj} = \frac{\frac{c_s}{c_n \tau_n} \left(\frac{j}{j_s(c_s)} - 1 \right) - \frac{1}{\tau_s}}{\frac{c_s}{c_n} \left(\frac{j}{j_s(c_s)} - 1 \right) - 1} \quad , \quad (6)$$

with $c_n = c_0 - c_s$ and j_s given by Eq.(5).

For j increasing from 0, c_s decreases from $c_s(T)$, while $E_F - \mu$ increases from 0, proportionally to the length of the arrow linking P_n, P_s in Fig.1. In addition, since j_s will eventually vanish for $c_s \rightarrow 0$, as inferred from Eq.(5), j_s is bound to rise from $j_s = 0$ at A up to a maximum $j_s(c_m)$ at $c_m(T) < c_s(T)$ defined by $\frac{dj_s}{dc_s}(c_m) = 0$. In order to solve Eq.(6), $E_F - \mu$ will be replaced by its Taylor's expansion at first order with respect to $c_s - c_s(T)$

$$\frac{e^2}{m} (E_F - \mu) = \beta (c_s(T) - c_s) \Rightarrow c_m = \frac{2}{3} c_s(T) \quad , \quad (7)$$

with $\beta = \frac{e^2}{m} \left(\frac{\partial E_F}{\partial c_n}(c_n(T)) + \frac{\partial \mu}{\partial c_s}(c_s(T)) \right)$. Thus Eq.(6) has been integrated with $c_0 = 10^{28}/m^3, c_s(T) = .1c_0, \tau_s = 10^{-9}s, \tau_n = 10^{-4}\tau_s, \beta = 10^{-65}A^2 \times m^5$ and initial condition $c_s(j=0) = c_s(T)$. The resulting data $c_s(j), \sigma_e(j)$ ($\sigma_e = \sigma_n + \sigma_s^*$ refers to the effective conductivity) have been plotted in Figs.2,3, corresponding to $j \leq j_m$ or $j > j_m$, respectively, with j_m defined by $j_m = j_s(c_m)$.

For $j \leq j_m$, there is $\tau_s \left| \frac{\dot{c}_s}{c_s} \right| \ll 1$, so that Eq.(4) yields $\sigma_s^* \approx \sigma_s$ and Eq.(6) reduces to

$$\frac{j_s(c_s)}{j} = 1 + \frac{\sigma_n}{\sigma_s} = 1 + \frac{\tau_n}{\tau_s} \left(\frac{c_0}{c_s} - 1 \right) \quad . \quad (8)$$

Likewise, Eq.(8) implies $j_s \approx \sigma_s E \Rightarrow \left| \frac{E_{s \rightarrow n}}{E} \right| \ll 1$, which confirms the validity of a previous assumption. As γ does not show up in Eq.(8), there is a one-to-one correspondence between j and c_s , as seen in Fig.2. Moreover,

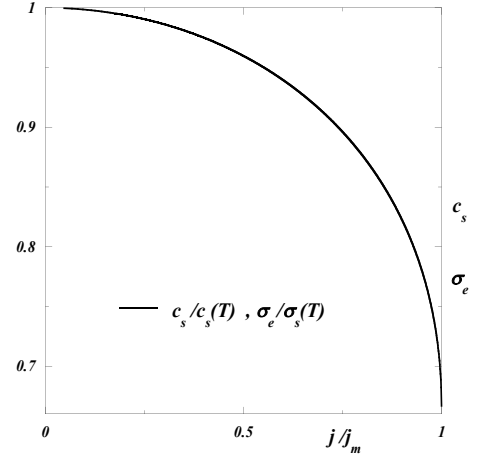


FIG. 2. plots of $c_s(j), \sigma_e(j)$ for $j \leq j_m$, as a solid line; the results have been found to be independent from γ in accordance with Eq.(8)

$\tau_n \ll \tau_s$ entails that $j_s \approx j$, so that the $c_s(j), \sigma_e(j)$ plots cannot be distinguished from each other. Note that $\frac{dc_s}{dj}(j=0) = 0$, while $\left| \frac{dc_s}{dj} \right|$ becomes very large for $j \rightarrow j_m$.

However, when j keeps growing beyond j_m , $j_s \approx j$ is no longer valid because of $j_s \leq j_m < j$. Consequently, as seen in Fig.3, $c_s(j)$, obtained by integrating Eq.(6) for $j > j_m$, falls steeply from $c_s(j_m) = c_m$ down to 0, and σ_e sinks by the ratio $\frac{c_s(T)\tau_s}{c_0\tau_n} = 10^3$ from $\sigma_e(T) \approx \sigma_s(T)$ down to $\sigma_e(T_c) = \frac{c_0 e^2 \tau_n}{m}$, typical of the normal metal. Meanwhile j undergoes a tiny increase from j_m up to j_M , with j_M being weakly γ dependent, i.e. $j_M/j_m - 1 \approx 10^{-7}, 10^{-8}$ for $\gamma = 2 \times 10^9, 2 \times 10^7 A/(m^2 \times s)$, respectively (see Fig.3). Finally, due to $j_M \approx j_m = j_s(c_m)$, $j_M(T < T_c)$ reads

$$j_M = e c_m(T) \sqrt{\frac{2}{m} (E_F(T, c_0 - c_m(T)) - \mu(c_m(T)))} \quad .$$

Integrating Eq.(6) from $j = j_M$ down to $j = 0$ with the initial condition $c_s = c_s(j_M) \approx 0$, while keeping γ *unaltered*, will produce the same solution $c_s(j)$, as displayed in Figs.2,3. This shows that the superconducting-normal transition is *reversible* and there is a *one-to-one* correspondence between j and c_s , provided that γ keeps the *same* value for j increasing from 0 up to j_M or decreasing from j_M down to 0, as well. This property holds actually for any $j(t)$, such that $j(t) = j(t_p - t), \forall t \in [0, t_p/2]$, with t_p taken such that $j(t_p/2) = j_M$.

Due to $j_s \approx j$ for $j < j_m$, measuring $\sigma_e(j)$ and the j dependent London length, which gives access^{14,15} to c_s , would enable one to chart $E_F(T, c_n) - \mu(c_s)$ with help of Eq.(5). Given the highest observed j_M values, Eq.(5) provides the estimate $E_F(T, c_n) - \mu(c_s) < 10^{-5}eV$. It is noticeable that the conductivity, decreasing by several orders of magnitude for $j \rightarrow j_M$, as seen above, and for $T \rightarrow T_c^-$, as discussed elsewhere¹⁵, is to be ascribed, in

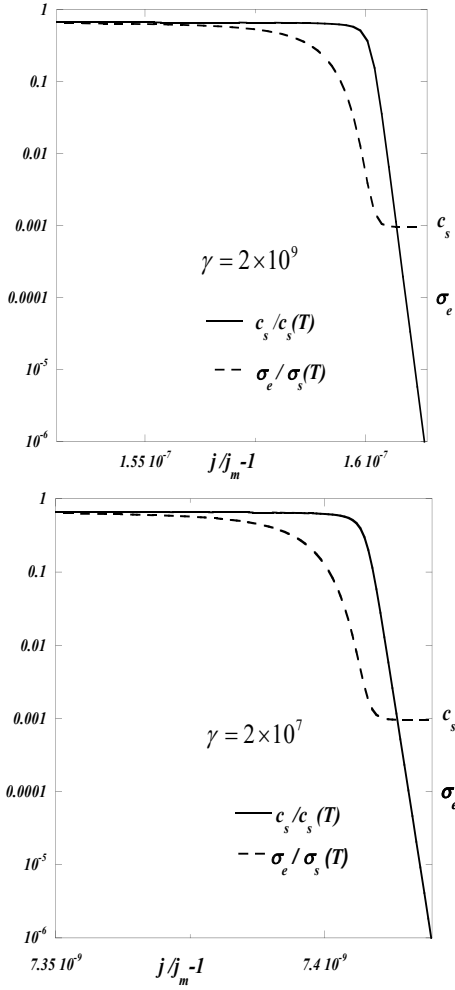


FIG. 3. plots of $c_s(j), \sigma_e(j)$ for $j > j_m$, as a solid and dashed line, respectively; the calculation has been done for two values $\gamma = 2 \times 10^7, 2 \times 10^9 A/(m^2 \times s)$

both cases, to c_s decreasing very steeply down to 0.

III. THERMODYNAMICAL DISCUSSION

As recalled above, the work $W_{s \rightarrow n}$, performed by $f_{s \rightarrow n}$, whereby all of superconducting electrons are turned into normal ones via an isothermal process²⁷, is equal to the difference of free energy per unit volume ΔF , between the normal and superconducting states. Due to the very definitions of E_F, μ , the work $W_{s \rightarrow n}$ is thence deduced to read

$$W_{s \rightarrow n} = \int_0^{c_s(T)} (E_F(T, c_0 - u) - \mu(u)) du \quad . \quad (9)$$

In addition, Eq.(9) implies that $W_{s \rightarrow n} = -W_{n \rightarrow s}$, consistently with the reversible nature of the transition.

$W_{s \rightarrow n}$ can be also achieved alternatively by using the definition of $\Delta F = \Delta \mathcal{E} + T \Delta S$, with \mathcal{E}, S being, respectively, the total energy and entropy of the sample, i.e.

including all of the *lattice* and *electron* degrees of freedom. $\Delta \mathcal{E}, \Delta S$ will be calculated by working out the detailed thermal balance over the following trajectory : the sample is first taken at $T < T_c$ and heated up to T_c with $j = 0$. Hence, the associated $\Delta \mathcal{E}_1, \Delta S_1$ read

$$\begin{aligned} \Delta \mathcal{E}_1 &= \int_{T_c}^T (C_\phi(u) + C_s(u)) du \\ \Delta S_1 &= \int_{T_c}^T (C_\phi(u) + C_s(u)) \frac{du}{u} \end{aligned} \quad , \quad (10)$$

with $C_\phi(T), C_s(T)$ standing for the respective contributions²⁶ to the specific heat of the phonons (Debye) and of the conduction electrons in the superconducting state; then let the sample be cooled down back to T , while being flown through by a current density $j \geq j_M(T)$, so that the sample remains normal down to T . The associated $\Delta \mathcal{E}_2, \Delta S_2$ read then

$$\begin{aligned} \Delta \mathcal{E}_2 &= \int_{T_c}^T (C_\phi(u) + C_n(u)) du \\ \Delta S_2 &= \int_{T_c}^T (C_\phi(u) + C_n(u)) \frac{du}{u} \end{aligned} \quad , \quad (11)$$

with $C_n(T)$ standing for the T linear, specific heat of a Fermi gas²⁶, which is known to be independent from j , like $C_\phi(T)$. At last, the searched expressions read¹¹

$$\begin{aligned} E_b(T) &= \Delta \mathcal{E}_1 + \Delta \mathcal{E}_2 = \int_{T_c}^T (C_s(u) - C_n(u)) du \\ W_{s \rightarrow n}(T) &= \Delta \mathcal{E}_1 + T \Delta S_1 + \Delta \mathcal{E}_2 + T \Delta S_2 \\ &= \int_{T_c}^T (C_s(u) - C_n(u)) \left(1 - \frac{T}{u}\right) du \end{aligned} \quad , \quad (12)$$

with $E_b(T)$ being the binding energy of the superconducting phase with respect to the normal one at T . Noteworthy is that the superconducting phase being stable ($\Leftrightarrow E_b(T) > 0$) requires $C_s(T) > C_n(T)$ in Eq.(12), which is confirmed experimentally^{1,26}, i.e. $C_s(T_c) \approx 3C_n(T_c)$.

$W_{s \rightarrow n}$ can actually be measured directly by feeding a growing current $I(t) = \pi r_0^2 \gamma t$ into the superconducting sample, from $t = 0$ until $t = \frac{t_p}{2}$ with $I(\frac{t_p}{2}) = \pi r_0^2 j_M(T)$, so that the sample goes normal at $\frac{t_p}{2}$ (this is referred to as the Silsbee effect¹). Then $I(t)$ is reduced, like $I(t) = \pi r_0^2 \gamma (t_p - t)$, from $I(\frac{t_p}{2})$ down to $I(t_p) = 0$. The work $W(t_p)$, performed by the electric field E from $t = 0$ until $t = t_p$, reads then

$$\begin{aligned} W(t_p) &= W_1 + W_2 \\ W_1 &= \int_0^{\frac{t_p}{2}} U(t)I(t)dt \quad , \quad W_2 = \int_{\frac{t_p}{2}}^{t_p} U(t)I(t)dt \end{aligned} \quad , \quad (13)$$

with $U = El$ and l being the measured voltage drop across the sample and its length, respectively. Moreover, owing to Eq.(4), W_1, W_2 can be recast as

$$\begin{aligned} \frac{W_1}{\pi r_0^2 l} &= \int_0^{\frac{t_p}{2}} \left(\frac{j_n^2}{\sigma_n} + \frac{j_s^2}{\sigma_s} + j_s E_{s \rightarrow n} \right) dt \\ \frac{W_2}{\pi r_0^2 l} &= \int_{\frac{t_p}{2}}^{t_p} \left(\frac{j_n^2}{\sigma_n} + \frac{j_s^2}{\sigma_s} + j_s E_{n \rightarrow s} \right) dt \end{aligned} \quad . \quad (14)$$

Likewise, recalling that $j_n, \sigma_n, j_s, \sigma_s$ have been shown above to depend on j only, if γ is kept fixed, and furthermore

$$\begin{aligned} W_{s \rightarrow n} &= \int_0^{\frac{t_p}{2}} j_s E_{s \rightarrow n} dt \quad , \quad W_{n \rightarrow s} = \int_{\frac{t_p}{2}}^{t_p} j_s E_{n \rightarrow s} dt \\ W_{s \rightarrow n} &= -W_{n \rightarrow s} \end{aligned} \quad ,$$

enables us to recast W_1, W_2 as

$$\frac{W_1}{\pi r_0^2 l} = Q_1 + W_{s \rightarrow n} \quad , \quad \frac{W_2}{\pi r_0^2 l} = Q_1 - W_{s \rightarrow n} \quad , \quad (15)$$

$$Q_1 = \int_0^{j_M(T)} \left(\frac{j_n^2}{\sigma_n} + \frac{j_s^2}{\sigma_s} \right) \frac{dj}{\gamma}$$

with Q_1 expressing the Joule heat, released¹⁶ through process I per unit volume for $t \in [0, t_p/2]$. Finally it ensues from Eq.(15)

$$\frac{W_1 - W_2}{2\pi r_0^2 l} = \int_T^{T_c} (C_s(u) - C_n(u)) \left(1 - \frac{T}{u} \right) du \quad . \quad (16)$$

The validity of Eq.(16) should be checked experimentally first in a superconducting material, for which accurate data are available for C_s, C_n and thence T_c is low²⁶ enough for $C_s > C_\phi, C_n > C_\phi$. Accordingly, Al ($T_c = 1.19K$) might be a good candidate. In case of a successful test, Eq.(16) might then provide with a rather *unique* access to C_s in high T_c materials, for which the direct measurement of C_s proves unreliable²⁹, due to $C_s \ll C_\phi$. Note that C_n can always be measured at low T by feeding into the sample a current density $j > j_M(T)$, whereby the sample goes normal even at $T < T_c$, because C_n is j independent, unlike C_s , and extrapolated further to higher T , by taking advantage of its T linear behaviour²⁶.

Although the superconducting to normal transition and ice melting into water are both first order processes, they differ in two respects :

- the role of the latent *heat*, typical of all usual first order transitions (melting or vaporisation), is played here by the latent *work* $W_{s \rightarrow n}$, because the superconducting-normal transition is controlled by *current* rather than by *temperature*;
- ice and water are separated by a clear-cut interface, whereas the mixture of superconducting and normal electrons is homogeneous. Consequently, the chemical potentials of ice and water remain uniquely defined all over the melting process, while E_F, μ vary continuously with $c_s \in [0, c_s(T < T_c)]$.

IV. CRITICAL CURRENT

As shown elsewhere¹⁶, the *bound electron* current j_s will turn out to be *persistent*, only if the necessary condition $\sigma_s + \sigma_J > 0$, with $\sigma_J < 0$ being the conductivity characterising process II of the Joule effect, is fulfilled. It conveys the physical meaning that the negative Joule heat, released via the anomalous process II, typical of superconductors, should prevail over the positive one, stemming from the regular process I. Since σ_J reads¹⁶ as $\sigma_J = -\frac{(ev)^2 \tau_s}{|\frac{\partial \mu}{\partial c_s}|}$ with $mv^2 \approx 1eV$, the inequality $\sigma_s + \sigma_J > 0$ can be recast as

$$r(c_s) = \frac{c_s}{mv^2} \left| \frac{\partial \mu}{\partial c_s} \right| > 1 \quad . \quad (17)$$

As it will appear below that $\frac{\partial \mu}{\partial c_s}$ remains finite for $c_s \rightarrow 0$, the inequality (17) is bound not to hold any more for $c_s < c_c$ with the critical concentration c_c defined by $r(c_c) = 1$. To proceed further, c_c must be assessed, which requires to reckon $\frac{\partial \mu}{\partial c_s}$. The only practical tool for this purpose is the BCS scheme¹³, but for some reason to become clear below, we shall refrain from using it, and rather develop our own procedure.

Thus let us consider a three-dimensional crystal containing N sites and $2n$ itinerant electrons with $N \gg 1, n \gg 1$ ($\Rightarrow c_s = 2n/N$). These electrons of spin $\sigma = \pm 1/2$ populate a single band, accomodating at most two electrons per site ($\Rightarrow n \leq N$). The independent electron motion is described, in reciprocal space, by the Hamiltonian H_d

$$H_d = \sum_{k, \sigma} \varepsilon(k) c_{k, \sigma}^+ c_{k, \sigma} \quad , \quad (18)$$

for which $\varepsilon(k), k$ are the one-electron, spin-independent energy ($\Rightarrow \varepsilon(k) = \varepsilon(-k)$) and a vector of the Brillouin zone, respectively, and the sum over k is to be carried out over the whole Brillouin zone. Then $c_{k, \sigma}^+, c_{k, \sigma}$ are one-electron creation and annihilation operators on the Bloch state $|k, \sigma\rangle$

$$|k, \sigma\rangle = c_{k, \sigma}^+ |0\rangle \quad , \quad |0\rangle = c_{k, \sigma} |k, \sigma\rangle \quad ,$$

with $|0\rangle$ being the no electron state. They enable us to introduce the two-electron creation and annihilation operators^{13,28,30} $b_{K, k}^+ = c_{k, +}^+ c_{K-k, -}^+, b_{K, k} = c_{K-k, -} c_{k, +}$, which operate on hard-core bosons and thence do not fulfill the boson commutation rules. The interacting electron motion is governed by a truncated Hubbard Hamiltonian H_K , used previously^{13,30}

$$H_K = \sum_k \varepsilon(K, k) b_{K, k}^+ b_{K, k} + \frac{U}{N} \sum_{k, k'} b_{K, k}^+ b_{K, k'} \quad , \quad (19)$$

with $\varepsilon(K, k) = \varepsilon(k) + \varepsilon(K - k)$ and U being the Hubbard coupling constant. Unlike previous authors^{2,3,13,28}, we shall consider *both* cases $U > 0, U < 0$.

The eigenstate of the Schrödinger equation, pertaining to a single bound pair, $(H_K - \varepsilon_c(K)) \varphi_c = 0$, is known as the Cooper pair²⁸ state $\varphi_c = \sum_k \frac{b_{K, k}^+}{\varepsilon_c(K) - \varepsilon(K, k)} |0\rangle$, with the eigenenergy $\varepsilon_c(K)$ being the solution of

$$\frac{1}{U} = \frac{1}{N} \sum_k \frac{1}{\varepsilon_c(K) - \varepsilon(K, k)} = \int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{\varepsilon_c(K) - \varepsilon} d\varepsilon. \quad (20)$$

$\pm t_K$ are the upper and lower bounds of the two-electron band, i.e. the maximum and minimum of $\varepsilon(K, k)$ over k , whereas $\rho_K(\varepsilon)$ is the corresponding two-electron density of states. For the sake of illustration, we shall solve Eq.(20) for $\rho_K(\varepsilon) = \frac{2}{\pi t_K} \sqrt{1 - \left(\frac{\varepsilon}{t_K}\right)^2}$, $t_K = t \cos(Ka/2)$, where t, a are the one-electron bandwidth and the lattice parameter, respectively. The dispersion curves $\varepsilon_c(K)$ are

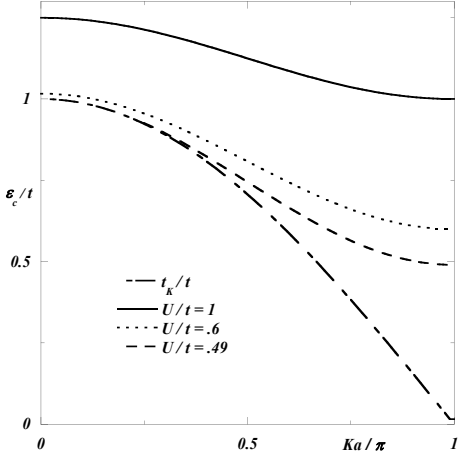


FIG. 4. dispersion curves of t_K as a dashed-dotted line and of $\varepsilon_c(K)$ as solid, dashed and dotted lines, associated with various U values, respectively

given in Fig.4 for $U > 0$ only, because it can be deduced from Eq.(20) and $\rho_K(\varepsilon) = \rho_K(-\varepsilon)$ that $\varepsilon_c(K, U) = -\varepsilon_c(K, -U)$. A remarkable feature is that $\varepsilon_c(K) \rightarrow t_K$, i.e. the upper bound of the two-electron band, for U decreasing toward $t_K/2$, so that there is *no* Cooper pair solution for $U < t_K/2$ (accordingly, the dashed curve is no longer defined in Fig.4 for $\frac{Ka}{\pi} < .13$), in marked contrast with the opposite conclusion reached elsewhere²⁸, that there is a Cooper pair, even for $U \rightarrow 0$. This discrepancy results from the three-dimensional Van Hove singularities, showing up at both two-electron band edges $\rho_K(\varepsilon \rightarrow \pm t_K) \propto \sqrt{t_K - |\varepsilon|}$, unlike the two-electron density of states, used previously²⁸, which displayed no such singularity.

H_K operates within the Hilbert space S_K . A typical vector of its basis reads $\varphi = \prod_{i=1, \dots, m} b_{K, k_i}^+ |0\rangle$ with m being any integer. We shall look for a variational approximation φ_v of the single^{31,32} bound eigenstate of H_K inside the subset $\{\varphi_v\} \subset S_K$, characterized by

$$\langle \varphi_v | b_{K, k}^{(+)} | \varphi_v \rangle = (n_k (1 - n_k))^\alpha, \quad \forall \varphi_v \in \{\varphi_v\} .$$

The real parameter α will be assigned shortly and $n_k = \langle \varphi_v | b_{K, k}^+ b_{K, k} | \varphi_v \rangle$. The pair number operator $b_{K, k}^+ b_{K, k}$ has two eigenvalues 0, 1, associated with $|0\rangle$ and $b_{K, k}^+ |0\rangle$, respectively, so that $0 \leq n_k \leq 1$ and $\sum_k n_k = n$. The energy of φ_v per site reads

$$\mathcal{E} = \frac{\langle \varphi_v | H_K | \varphi_v \rangle}{N} = \sum_k \varepsilon(K, k) \frac{n_k}{N} + U \Delta^2$$

$$\Delta = \sum_k \frac{(n_k (1 - n_k))^\alpha}{N} .$$

Hence minimising \mathcal{E} ($\Rightarrow d\mathcal{E} = 0$), under the constraint of n kept constant ($\Rightarrow dn = 0$), yields

$$\varepsilon(K, k) + 2\alpha U \Delta \frac{1 - 2n_k}{(n_k (1 - n_k))^{1-\alpha}} = \lambda ,$$

with $\lambda = \frac{\partial \mathcal{E}}{\partial n_k}, \forall k$ being a Lagrange multiplier, which implies that $\lambda = \frac{\partial \mathcal{E}}{\partial n} = 2\mu (c_s = \frac{2n}{N})$. The α value

will be assigned now by checking consistency with the Cooper pair properties in the limit $n \rightarrow 0 \Rightarrow n_k \rightarrow 0 \Rightarrow n_k \propto (2\mu - \varepsilon(K, k))^{-1}$. Comparing with $n_k = \langle \varphi_c | b_{K, k}^+ b_{K, k} | \varphi_c \rangle \propto (\varepsilon_c(K) - \varepsilon(K, k))^{-2}$, inferred from Eq.(20), yields finally $\alpha = 1/2$ and $\varepsilon_c(K) = 2\mu (c_s = 0)$, a conclusion which had already been reached by an independent rationale¹⁶. Hence, our variational procedure can be summarised, with help of notations introduced elsewhere², as follows

$$\tan 2\theta_k = \frac{2U\Delta}{2\mu - \varepsilon(K, k)} , \quad n_k = \sin^2 \theta_k$$

$$\Delta = \sum_k \frac{\sin 2\theta_k}{2N} = \int_{-t_K}^{t_K} \frac{\sin 2\theta(\varepsilon)}{2} \rho_K(\varepsilon) d\varepsilon , \quad (21)$$

$$c_s = 2 \sum_k \frac{\sin^2 \theta_k}{N} = 2 \int_{-t_K}^{t_K} \sin^2 \theta(\varepsilon) \rho_K(\varepsilon) d\varepsilon$$

with $0 \leq \theta_k \leq \frac{\pi}{2}$. The formulae in Eqs.(21) are found to be identical to those of BCS^{2,3,13}. As an illustrative example, Eqs.(21) have been solved for $\mu(c_s), \Delta(c_s)$ and $r(c_s)$ defined by Eq.(17), with $U > 0$ and $c_s < 1$ electron per site, only, because it can be deduced from Eqs.(21) and $\rho_K(\varepsilon) = \rho_K(-\varepsilon)$ that $\mu(c_s, U) = -\mu(c_s, -U) = -\mu(2 - c_s, U)$. The results, presented in Fig.5, exhibit $\frac{\partial \mu}{\partial c_s}$ almost independent from c_s and $\Delta(c_s \rightarrow 0) \propto \sqrt{c_s}$. An important inequality, holding for $U > 0$ and $U < 0$ as well, can be deduced from $\mu(c_s, U) = -\mu(c_s, -U)$ and Fig.5

$$U \frac{\partial \mu}{\partial c_s} < 0 . \quad (22)$$

Note that for $K = \frac{\pi}{a}$, the two-electron band is dispersionless because of $t_{K=\frac{\pi}{a}} = 0$. Then applying Eqs.(21) to the $K = \frac{\pi}{a}$ case gives $\Delta = \frac{\sin 2\theta}{2}$ and finally $\mu = \frac{U}{2} (1 - c_s)$, the validity of which can be checked independently, because the n -pair, bound eigenstate of $H_{K=\frac{\pi}{a}}$ is known³⁰ to read $\varphi = \sum_{i=1, \dots, d} \frac{\varphi_i}{\sqrt{d}}$, with $d = \binom{N}{n}$, $\varphi_i = \prod_{l=1, \dots, n} b_{\frac{\pi}{a}, k_{i_l}}^+ |0\rangle$ and the sum with respect to i runs over all of n pair combinations $\{b_{\frac{\pi}{a}, k_{i_1}}^+, \dots, b_{\frac{\pi}{a}, k_{i_n}}^+\}$, chosen among N of available pairs. As each φ_i contributes $\frac{n}{d} (1 - \frac{n}{N}) U$ to \mathcal{E} , it can thence be inferred $\mathcal{E} = U \frac{c_s}{2} (1 - \frac{c_s}{2}) \Rightarrow \mu = \frac{\partial \mathcal{E}}{\partial c_s} = \frac{U}{2} (1 - c_s)$, which is seen to be identical to the above result, deduced from Eqs.(21). At last, there is $U \frac{\partial \mu}{\partial c_s} = -U^2/2 < 0$ in accordance with inequality (22).

Combining Eq.(20) with Taylor's expansions of $\sin 2\theta_k, \sin^2 \theta_k$, worked out from Eqs.(21), up to Δ^2 for $c_s \rightarrow 0 \Rightarrow \Delta \rightarrow 0$, leads to

$$\frac{1}{U} = \int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{\varepsilon_c(K) - \varepsilon} d\varepsilon$$

$$= \int_{-t_K}^{t_K} \left(1 - 2 \left(\frac{U\Delta}{2\mu - \varepsilon} \right)^2 \right) \frac{\rho_K(\varepsilon)}{2\mu - \varepsilon} d\varepsilon .$$

$$(U\Delta)^2 = \frac{c_s}{2 \int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{(\varepsilon_c(K) - \varepsilon)^2} d\varepsilon}$$

Subtracting the integrals equal to $1/U$ from each other, while taking advantage of $\mu(c_s \rightarrow 0) \rightarrow \varepsilon_c(K)/2$, gives in

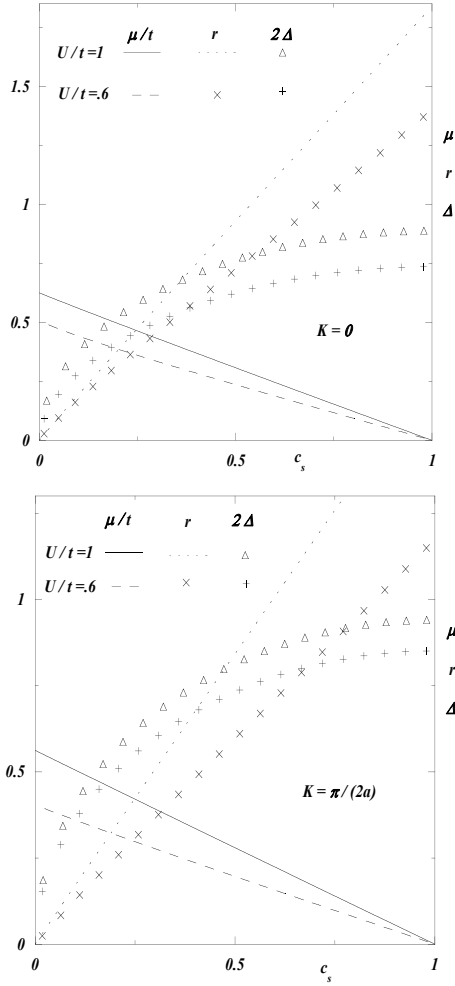


FIG. 5. plots of $\mu(c_s), \Delta(c_s), r(c_s)$ reckoned for $K = 0, \frac{\pi}{2a}$; the solid and dotted lines and the triangles, which pertain to μ, r, Δ , respectively, have been calculated with $U/t = 1$, whereas the dashed line and the $\times, +$ symbols, which refer to μ, r, Δ , respectively, have been calculated with $U/t = .6$; the r data have been calculated with $mv^2 = t/3$; $c_s = 1$ corresponds to one electron per site

turn

$$(U\Delta)^2 = \left(\frac{\varepsilon_c(K)}{2} - \mu \right) \frac{\int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{(\varepsilon_c(K) - \varepsilon)^2} d\varepsilon}{\int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{(\varepsilon_c(K) - \varepsilon)^3} d\varepsilon}.$$

Equating both expressions of $(U\Delta)^2$ yields finally

$$\frac{\partial \mu}{\partial c_s}(K, c_s = 0) = - \frac{\int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{(\varepsilon_c(K) - \varepsilon)^3} d\varepsilon}{2 \left(\int_{-t_K}^{t_K} \frac{\rho_K(\varepsilon)}{(\varepsilon_c(K) - \varepsilon)^2} d\varepsilon \right)^2}.$$

Note that $\left| \frac{\partial \mu}{\partial c_s}(K, c_s = 0) \right| \rightarrow \infty$ for $U \rightarrow t_K/2$ and

$U \frac{\partial \mu}{\partial c_s}(K, c_s = 0) < 0$ in accordance with inequality (22).

With help of Fig.5, c_c , defined by $r(c_c) = 1$ in Eq.(17), can now be assigned, for $K = 0$, to the values $.7, .54$,

and for $K = \frac{\pi}{2a}$, to the values $.85, .6$, associated with $U/t = .6, 1$, respectively. Noteworthy is that φ_v will sustain persistent currents or not, according to whether $c_s > c_c$ or $c_s < c_c$, although φ_v undergoes *no qualitative* change for $c_s = c_c$. Accordingly, it still obeys Eqs.(21) for $c_s > c_c$ and $c_s < c_c$, as well. Therefore, $\varphi_v(c_s < c_c)$ will be referred to below, as the many-bound-electron, *non-superconducting* (MBENS) state. Moreover, applying Eq.(5) for $c_s = c_c$, while taking advantage of the Sommerfeld integral²⁶ and Eq.(1), yields the critical current density as

$$j_c(T) = c_c e \sqrt{\frac{2}{m} (E_F(T, c_0 - c_c) - \mu(c_c))} \\ = \pi k_B e c_c \sqrt{\frac{\rho'(E_F^*)}{3m\rho(E_F^*)} (T_*^2 - T^2)}, \quad (23)$$

with $E_F^* = E_F(T_*, c_0 - c_c)$. $k_B, \rho(\varepsilon)$ designate Boltzmann's constant and the one-electron density of states and $\rho'(\varepsilon) = \frac{d\rho}{d\varepsilon}$, while $T_* < T_c$ is defined by $E_F(T_*, c_0 - c_c) = \mu(c_c) \Rightarrow c_s(T_*) = c_c$. The calculated behavior $j_c(T) \propto \sqrt{T_*^2 - T^2}$, resulting from Eq.(23), is found to agree with observation^{2-4,26}. Consequently, the MBENS state and the superconducting one can be observed for $T_* < T < T_c$ and $T < T_*$, respectively. In a low T_c metal such as Sn , c_s has been shown¹⁵ to grow steeply from $c_s(T_c) = 0$ up to $c_s(T_c - .04K) \approx c_s(0) \Rightarrow T_c - T_* < .04K$, so that T_c, T_* are unlikely to be resolved experimentally from each other. However $T_c - T_*$ will be argued in the next section to be quite sizeable in high T_c materials.

$\frac{\partial \mu}{\partial c_s} < 0$ has been shown¹⁶ to be a prerequisite for persistent currents. Hence, the inequality 22 entails $U > 0$. Besides, an additional setback of the assumption^{13,28} $U < 0 \Rightarrow \frac{\partial \mu}{\partial c_s} > 0$ is to preclude any thermal equilibrium for $T < T_c$. Here is a proof by contradiction. Let us assume that the BCS state is indeed in equilibrium at T_c , which implies $E_F(T_c, c_0) = \mu(c_s = 0)$, because of $c_s(T_c) = 0, c_n(T_c) = c_0$, in accordance with Eq.(1). When T decreases from T_c down to 0, charge conservation $c_0 = c_n(T) + c_s(T)$ entails

$$E_F(T) = E_F(T_c) - \frac{c_s(T)}{\rho(E_F(T_c))}, \quad \mu(T) = \mu(T_c) + \frac{\partial \mu}{\partial c_s} c_s(T),$$

for which we have used²⁶ $\frac{\partial E_F}{\partial c_s} = 1/\rho(E_F)$, while neglecting $\frac{\partial E_F}{k_B \partial T} \approx k_B T/E_F \ll 1$. Thus, $\frac{\partial \mu}{\partial c_s} > 0$ implies $E_F(T) < E_F(T_c) = \mu(T_c) < \mu(T)$, so that the equilibrium condition $\mu(c_s(T)) = E_F(T, c_0 - c_s(T))$ in Eq.(1) cannot be fulfilled for any $T < T_c$. *Q.E.D.*

V. HIGH- T_c COMPOUNDS

Overdoped high T_c compounds are known^{5-10,17,18,22,23} to undergo, at T_c , a crossover from a superconducting state of type II, observed for $T < T_c$, to an ill-understood state, which sustains no persistent current, but the conduction properties of which differ yet markedly from those of usual metals up to $T \gg T_c$:

- contrary to the conductivity expected to be low, given the high doping rate $> .15$, it is observed to be large;
- the Hall coefficient is found to be T dependent, which hints at a T dependent carrier concentration, unlike what is observed in usual metals and alloys, behaving like a Fermi gas²⁶ with T independent concentration.

Assuming $T_c = T_*$, both above mentioned features might be consistent with an electron system, comprising a Fermi gas *and* a MBENS state in respective concentration $c_n(T > T_*)$, $c_s(T)$ and fulfilling Eq.(1) with $c_0 = c_n(T) + c_s(T)$. As a matter of fact, $\tau_s \gg \tau_n$ entails¹⁴ that the large conductivity is settled by the MBENS electrons only and the Hall coefficient, dominated by j_s , is T dependent as is $c_s(T)$. The main virtue of such an assumption is that it lends itself to an experimental check, as shown below.

Consider a thermally isolated sample, flown through by $I(t) = \pi r_0^2 j(t)$ with $j(t) = \gamma t$, and taken at $t = 0$ in the thermal equilibrium state, represented by A in Fig.1, i.e. $T(t = 0) = T_*$, $I(t = 0) = 0$, $c_n(t = 0) = c_n(T_*)$, $c_s(t = 0) = c_0 - c_n(T_*)$. While $I(t)$ keeps growing, the bound electrons, pictured by Q_s in Fig.1, are turned into independent ones, depicted by Q_n , as explained in section 2. The experiment ends up at $t = t_f$, when Q_n , after traveling all along the dotted line, merges with C , referring to the normal state and thence characterized by $T(t_f) = T_f$, $c_n(t_f) = c_0$, $c_s(t_f) = 0$. Thus applying the first law of thermodynamics to this adiabatic process yields

$$\int_{T_*}^{T_f} C_\phi(T) dT = Q_1 + Q_2 \quad , \quad Q_2 = \int_0^{t_f} \frac{j_s^2(t)}{\sigma_J} dt \quad , \quad (24)$$

$$Q_1 = \int_0^{t_f} \frac{U(t)}{l} j(t) dt = \int_0^{t_f} \left(\frac{j_n^2(t)}{\sigma_n} + \frac{j_s^2(t)}{\sigma_s} \right) dt \quad ,$$

where $Q_1 > 0$, $Q_2 < 0$ stand for the Joule heat released through processes¹⁶ I and II, respectively, and $C_n(T > T_*) \ll C_\phi(T)$, $C_s(T > T_*) \ll C_\phi(T)$, $W_{s \rightarrow n} \ll Q_1$ have been neglected. Derivating Eq.(24) with respect to t gives finally

$$C_\phi(T) \dot{T} = \frac{U(t)}{l} j(t) + \frac{j_s^2}{\sigma_J} = \frac{j_n^2}{\sigma_n} + j_s^2 \left(\frac{1}{\sigma_s} + \frac{1}{\sigma_J} \right) \quad , \quad (25)$$

with $\dot{T} = \frac{dT}{dt}$. Because of $\frac{1}{\sigma_s} + \frac{1}{\sigma_J} > 0$, due to the very definition of T_* , we predict $\dot{T} > 0 \Rightarrow T_f > T_*$, with $\sigma_J < 0 \Rightarrow C_\phi(T) \dot{T} < \frac{U(t)}{l} j(t)$. Despite $\dot{T} > 0$ like in a usual metal, the latter inequality would rather read $C_\phi(T) \dot{T} = \frac{U(t)}{l} j(t)$, if the same experiment were carried out in a normal conductor. Conversely, would the experiment be performed at $T < T_* \Rightarrow \frac{1}{\sigma_s} + \frac{1}{\sigma_J} < 0$, we should observe¹⁶ $\dot{T} < 0$, as remarked by De Gennes too (see⁴ footnote in p.18). Besides, the sign of \dot{T} is independent of that of \dot{I} , because the Joule effect is *irreversible*. At last, due to the high doping rate, the local electron concentration is likely to display spatial fluctuations, which

should eventually result into a sample, comprising both superconducting *and* MBENS domains. This case could be brought to experimental evidence by observing different values of \dot{T} in Eq.(25), according to whether a dc ($\Rightarrow \dot{T}_{dc}$) or ac ($\Rightarrow \dot{T}_{ac}$) current is fed into the sample, because superconducting domains will contribute to the Joule effect *only* for ac current, whereas MBENS ones will do in *both* cases. Thus we predict $\dot{T}_{ac} < \dot{T}_{dc}$.

VI. MAGNETOELASTICITY

Magnetoelastic effects were reported^{24,25} long ago, in superconducting metals, at $T \leq T_c$ and atmospheric pressure : when the magnetic field H starts growing from 0, the sample first expands by a tiny amount ($\approx 10^{-7}$) and then shrinks abruptly for H reaching some critical value $H_c(T)$, at which the sample goes normal. Actually, because the superconducting electrons are known¹⁻⁴ to be in a macroscopic singlet spin state, H has no direct sway on them, but merely induces an eddy current according to Faraday's law¹². This current, responsible for the Meissner effect, turns superconducting electrons into normal ones, as discussed in section 2, but only within a thin film of thickness λ_M , located at the outer edge of the sample¹². Meanwhile, the partial pressure, stemming from the electrons, is altered, as will be shown now.

The free energy, associated with a sample of volume V , containing n conduction electrons ($\Rightarrow \frac{n}{V} = c_0 = c_n + c_s$), reads $V F(T, c_0)$ with $F(T, c_0) = F_n(T, c_n) + \mathcal{E}_s(c_s)$ being the electronic free energy per unit volume. The partial pressure p_e , exerted by the electrons, reads²⁷ then

$$p_e(H \neq 0) = -\frac{\partial(VF)}{\partial V} = c_0 \frac{\partial F}{\partial c_0} - F = c_n E_F(T, c_n) - F_n + c_s \mu(c_s) - \mathcal{E}_s \quad , \quad (26)$$

with $c_n > c_n(T)$, $F_n = \int_0^{c_n} E_F(T, u) du$, $c_s = c_0 - c_n$, $\mathcal{E}_s = \int_0^{c_s} \mu(u) du$.

Eq.(26) implies

$$\frac{\partial p_e}{\partial c_n} = c_n \frac{\partial E_F}{\partial c_n} - c_s \frac{\partial \mu}{\partial c_s} \quad .$$

Besides, $\frac{\partial E_F}{\partial c_n} = \frac{1}{\rho(E_F)}$, $\frac{\partial \mu}{\partial c_s} < 0$ entail $\frac{\partial p_e}{\partial c_n} > 0$. Since c_n grows at the expense of c_s for increasing H , the inequality $\frac{\partial H}{\partial c_n} > 0$ is always valid, which implies at last $\frac{\partial p_e}{\partial H} > 0$, in agreement with the observed H induced expansion^{24,25}.

For $H = H_c(T)$, the sample goes normal, so that H penetrates suddenly into bulk matter and polarises the whole set of normal electrons in concentration c_0 . The associated paramagnetic energy per unit volume reads²⁶ $\mathcal{E}_H = -\frac{(\mu_B H)^2}{2} \rho(E_F(T, c_0))$ with μ_B being the Bohr magneton. Because Pauli's susceptibility is T independent²⁶, \mathcal{E}_H is also equal to the magnetic contribution to the free energy, so that the partial pressure p_H , associated with H , reads

$$p_H = c_0 \frac{\partial \mathcal{E}_H}{\partial c_0} - \mathcal{E}_H = \frac{(\mu_B H)^2}{2} \left(\rho(E_F) - c_0 \frac{\rho'(E_F)}{\rho(E_F)} \right) \quad ,$$

with $E_F = E_F(T, c_0)$. As the sample was reported^{24,25} to shrink at $H_c(T)$, this implies $p_H < 0$, which can be realized only if $E_F(T, c_0)$ lies close to a Van Hove singularity at $\varepsilon_{VH} \Rightarrow \rho'(E_F) \propto (E_F - \varepsilon_{VH})^{-1/2} \gg 1$.

This kind of H driven experiment provides merely qualitative information, because of several drawbacks, related to the Meissner effect¹², as recalled in section 1. Consequently, the critical field $H_c(T)$ is ill-defined. To buttress this conclusion, we shall calculate $H(r)$ induced by the homogeneous current density j_c , parallel to the z axis. $H(r)$ is normal¹² to the unit vectors along the r and z coordinates and there is $H = rj_c/2$, thanks to the Ampère-Maxwell equation. Hence, H is seen to vary from $H(r=0) = 0$ up to $H(r_0) = r_0j_c/2$, so that H_c cannot be defined in a *unique* way, unlike $j_c(T)$. Likewise superconductors of type II make this proof more cogent, inasmuch as the whole superconducting sample is known¹⁻⁴ to turn continuously normal over a *broad* range of critical values $H_c \in [H_{c1}, H_{c2}]$ with $H_{c1} \ll H_{c2}$.

VII. CONCLUSION

A unified picture, accounting for low and high T_c superconductivity as well, has been developed. The physical significance of two different critical temperatures T_*, T_c with $T_* < T_c$, characterizing the electrodynamic

cal behavior of superconducting materials, has been analyzed. Whereas no persistent current can be observed for $T > T_*$, T_c is the upper bound of the MBENS state ($\Leftrightarrow c_s(T \geq T_c) = 0$) and is also identical to the usual critical temperature. The expression of the maximum persistent current $j_c(T)$ has been worked out and found to agree with observation. Unlike the normal current j_n , the bound electron current j_s does not depend on the applied electric field, but rather on c_s . The many-body wave-function, describing the motion of bound electrons, is identical for both superconducting ($c_s > c_c$) and MBENS ($c_s < c_c$) states, and accurately approximated by the BCS variational scheme. Conversely, the critical field H_c has been shown to lack a unique definition. Whereas T_*, T_c are unlikely to be resolved from each other in conventional superconductors due to the steep variation of $c_s(T \rightarrow T_c)$, T_c/T_* may be > 10 in high T_c compounds. Moreover, their peculiar conduction properties in the contentious^{17,18,22,23} range $T \in [T_*, T_c]$ have been ascribed to a MBENS state and an experiment, taking full advantage of the interplay between the usual and anomalous Joule effects¹⁶, has been outlined to check the validity of this assumption. The merit of a current driven experiment over a H driven one has been emphasized. At last, it has been shown that a *repulsive* ($U > 0$) Hubbard coupling is a prerequisite for superconductivity at thermal equilibrium, in accordance with the Coulomb force and Eq.(1).

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